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FDW2501N

FAIRCHILD SEMICONDUCTOR

Dual N-Channel 2.5V Specified PowerTrench[®] MOSFET

General Description

This N-Channel 2.5V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (2.5V - 12V).

Applications

- · Load switch
- Motor drive
- DC/DC conversion
- Power management

Features

- 6 A, 20 V. $\begin{array}{l} R_{DS(ON)} = 0.018 \; \Omega \; @ \; V_{GS} = 4.5 V \\ R_{DS(ON)} = 0.028 \; \Omega \; @ \; V_{GS} = 2.5 V \end{array}$
- Extended V_{GSS} range (±12V) for battery applications.
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- Low profile TSSOP-8 package





Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DSS}	Drain-Sou	rce Voltage		20	V
V _{GSS}	Gate-Sour	Source Voltage		±12	V
I _D	Drain Curr	ent – Continuous	(Note 1a)	6	А
		– Pulsed		30	
P _D	Power Dis	sipation	(Note 1a)	1.0	W
			(Note 1b)	0.6	
T _J , T _{STG}	Operating	and Storage Junction Tempe	rature Range	-55 to +150	°C
Therma R _{0JA}	Thermal R	cteristics	nt (Note 1a) (Note 1b)	125 208	°C/W
Packag	e Marking	ng and Ordering In	formation Reel Size	Tape width	Quantity
Device	Marking	Devide		•	

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	1				
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 250 \mu A$	20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		12		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}} = 16 \text{ V}, \qquad V_{\text{GS}} = 0 \text{ V}$			1	μA
I _{GSS}	Gate-Body Leakage	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA
On Chara	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 250 \ \mu A$	0.4	0.9	1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C		-3.2		mV/°0
$R_{\text{DS(on)}}$	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 4.5 \ V, & I_D = 6.0 \ A \\ V_{GS} = 2.5 \ V, & I_D = 5.0 \ A \\ V_{GS} = 4.5 \ V, \ I_D = 6.0A, \ T_J {=} 125^\circ C \end{array} $		15.5 19.6 20	18 28 29	mΩ
I _{D(on)}	On-State Drain Current	$V_{GS} = 4.5 \text{ V}, \qquad V_{DS} = 5 \text{ V}$	30			Α
g fs	Forward Transconductance	$V_{DS} = 5 V$, $I_{D} = 6.0 A$		32		S
Dvnamic	Characteristics	·	•	•	•	•
Ciss	Input Capacitance	$V_{DS} = 10 V$, $V_{CS} = 0 V$.		1290		pF
Coss	Output Capacitance	f = 1.0 MHz		315		pF
C _{rss}	Reverse Transfer Capacitance	1		170		pF
R _G	Gate Resistance	$V_{GS} = 15 \text{ mV}, f = 1.0 \text{ MHz}$		2.0		Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time			10	18	ns
tr	Turn–On Rise Time			15	27	ns
t _{d(off)}	Turn-Off Delay Time			26	47	ns
t _f	Turn–Off Fall Time			9.5	19	ns
Qg	Total Gate Charge	$ \begin{array}{ll} V_{\text{DS}} = 10 \ V, & I_{\text{D}} = 6.0 \ \text{A}, \\ V_{\text{GS}} = 4.5 \ V & \end{array} $		12	17	nC
Q _{gs}	Gate-Source Charge			2.4		nC
Q_{gd}	Gate–Drain Charge			3.3		nC
Drain-So	ource Diode Characteristics	and Maximum Ratings				
rr	Diode Reverse Recovery Time	I _F = 6.0 A,		20		nS
),rr	Diode Reverse Recovery Charge	$d_{iF}/d_t = 100 \text{ A}/\mu\text{s}$		6.7	1	nC
ls	Maximum Continuous Drain-Source	e Diode Forward Current	1	1	0.83	Α
V _{SD}	Drain–Source Diode Forward	$V_{GS} = 0 \ V, ~~I_S = 0.83 \ A ~~(\text{Note 2})$		0.7	1.2	V

1. R_{8JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

a) R_{θJA} is 125°C/W (steady state) when mounted on a 1 inch² copper pad on FR-4.
b) R_{θJA} is 208°C/W (steady state) when mounted on a minimum copper pad on FR-4.

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%



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	Formative / In Design First Production Full Production Not In Production